

Low Noise, Wideband, High IP3 Monolithic Amplifier Die

PMA2-153LN-D+

50Ω 0.5 to 15 GHz



The Big Deal

- Ultra wideband, 0.5 to 15 GHz
- Flat gain over wideband, 16.7 dB with ± 3.3 dB
- Low noise figure, 2.6 dB at 8 GHz
- High IP3, up to +28 dBm

Product Overview

The PMA2-153LN-D+ is a PHEMT based wideband, low noise, flat gain MMIC amplifier die with a unique combination of low noise, high IP3, and flat gain over wideband making it ideal for sensitive, high-dynamic-range receiver applications. This design operates on a single 5V or 6V supply, is well matched for 50Ω.

Key Features

Feature	Advantages
Low noise <ul style="list-style-type: none"> • 2.2 dB at 2 GHz • 2.6 dB at 8 GHz 	Enables lower system noise figure performance.
High IP3 <ul style="list-style-type: none"> • +27.7 dBm at 2 GHz • +26.8 dBm at 8 GHz 	Combination of low noise and high IP3 makes this MMIC amplifier die ideal for use in low noise receiver front end (RFE) as it gives the user advantages of sensitivity and two-tone IM performance at both ends of the dynamic range.
Low operating voltage, 5V/6V.	Achieves high IP3 using low voltage.
Wide bandwidth with flat gain <ul style="list-style-type: none"> • ± 0.1 dB over 0.5 to 2 GHz • ± 0.7 dB over 0.5 to 6 GHz • ± 1.2 dB over 0.5 to 8 GHz • ± 3.3 dB over 0.5 to 15 GHz 	Enables usage in applications without external gain flattening networks.
Unpackaged die	Enables users to integrate amplifier die directly into hybrids.



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Product Features

- Low Noise figure, 2.6 dB at 8 GHz
- High IP3, up to +28 dBm
- Excellent Gain flatness, ± 3.3 dB over 0.5 to 15 GHz at 6V



Typical Applications

- WiFi
- WLAN
- UMTS
- LTE
- WiMAX
- S-band Radar
- C-band Satcom

+RoHS Compliant

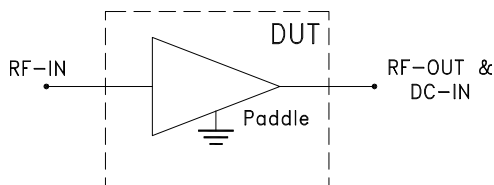
The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

Ordering Information: Refer to Last Page

General Description

The PMA2-153LN-D+ is a PHEMT based wideband, low noise, flat gain MMIC amplifier die with a unique combination of low noise, high IP3, and flat gain over wideband making it ideal for sensitive, high-dynamic range receiver applications. This design operates on a single 5V or 6V supply, is well matched for 50Ω.

Simplified Schematic and Pad Description



Pad Function	Description (See Figure 2)
RF-IN	Connects to RF input via C1
RF-OUT & DC-IN	Connects to RF out and V_{DD} via Bias-Tee
Ground	Connects to ground

Note: 1. Bond Pad material - Gold
2. Bottom of Die - Gold plated

Electrical Specifications¹ at 25°C, unless noted

Parameter	Condition (GHz)	V _{DD} =6.0			V _{DD} =5.0			Units
		Min.	Typ.	Max.	Min.	Typ.	Max.	
Frequency Range		0.5		15.0	0.5		15.0	GHz
Noise Figure	0.5		2.3			2.2		dB
	2.0		2.3			2.1		
	8.0		2.6			2.5		
	10.0		2.8			2.7		
	15.0		3.8			3.7		
Gain	0.5		19.0			18.1		dB
	2.0		18.9			18.0		
	8.0		16.8			16.0		
	10.0		16.0			15.3		
	15.0		12.5			11.7		
Input Return Loss	0.5		9.3			8.4		dB
	2.0		10.2			9.2		
	8.0		9.7			9.1		
	10.0		8.7			8.2		
	15.0		4.2			4.2		
Output Return Loss	0.5		13.5			11.7		dB
	2.0		13.0			11.6		
	8.0		22.9			21.0		
	10.0		17.4			17.1		
	15.0		6.9			6.2		
Output Power at 1dB Compression ²	0.5		15.3			14.2		dBm
	2.0		15.2			14.0		
	8.0		14.8			13.2		
	10.0		14.8			13.2		
	15.0		11.2			10.5		
Output IP3	0.5		27.3			24.7		dBm
	2.0		27.7			24.9		
	8.0		26.8			24.4		
	10.0		26.7			24.7		
	15.0		24.0			21.9		
Device Operating Voltage (V _{DD})			6.0			5.0		V
Device Operating Current (I _{DD})		—	66	85	—	50	—	mA
Device Current Variation vs. Temperature ³			-5.3			12.5		μA/°C
Device Current Variation vs. Voltage			0.0187			0.0187		mA/mV
Thermal Resistance, junction-to-ground lead			107			107		°C/W

1. Measured on Mini-Circuits Characterization Test Board. Die packaged in 2x2mm 8-lead MCLP package and soldered on MB-014-1. See Characterization Test Circuit (Fig. 1)

2. Current increases at P1dB up to 10mA typ. at 5Volts V_{DD}

3. (Current at 85°C - Current at -45°C)/130

Absolute Maximum Ratings⁴

Parameter	Ratings
Operating Temperature (ground lead)	-40°C to 85°C
Junction Temperature	160
Total Power Dissipation	0.7W
Input Power (CW), V _d =5.6V ⁵	+20 dBm (0.7 - 7.75 GHz) 5 minutes max. +22 dBm (7.75 - 15 GHz) 5 minutes max. +8 dBm (continuous)
DC Voltage	7V

4. Permanent damage may occur if any of these limits are exceeded. Electrical maximum ratings are not intended for continuous normal operation.

5. Measured on Mini-Circuits Characterization Test Board, MB-014-1



Characterization Test Circuit

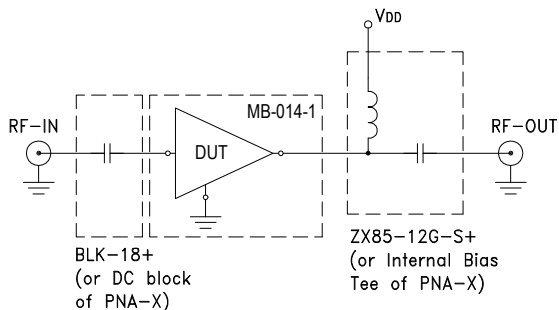


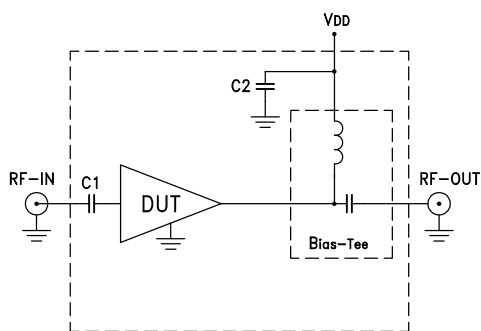
Fig 1. Characterization Circuit

Note: This block diagram is used for characterization. (DUT soldered on Mini-Circuits Characterization test board MB-014-1) Gain, Return loss, Output power at 1dB compression (P1 dB), output IP3 (OIP3) and noise figure measured using Agilent’s N5242A PNA-X microwave network analyzer.

Conditions:

1. Gain and Return loss: Pin= -25dBm
2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, 0 dBm/tone at output.

Recommended Application Circuit



Component	Size	Value
C1	0402	0.1 μ F
C2	0603	0.01 μ F

Fig 2. Application Circuit

Die Layout



Fig 3. Die Layout

Bonding Pad Position
(Dimensions in μm , Typical)

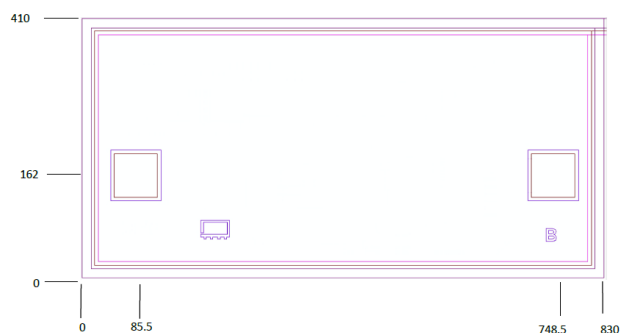


Fig 4. Bonding Pad Positions

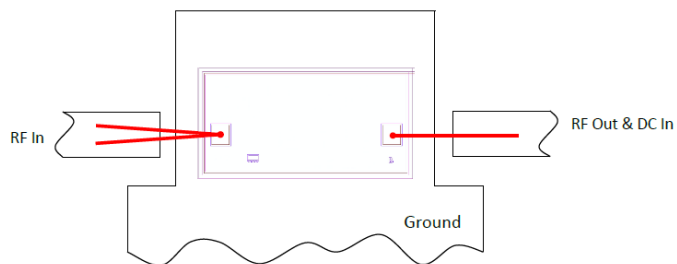
Critical Dimensions

Parameter	Values
Die Thickness, μm	100
Die Width, μm	410
Die Length, μm	830
Bond Pad Size	70 x 70

Assembly and Handling Procedure

- Storage**
Dice should be stored in a dry nitrogen purged desiccators or equivalent.
- ESD**
MMIC PHEMPT amplifier dice are susceptible to electrostatic and mechanical damage. Die are supplied in antistatic protected material, which should be opened in clean room conditions at an appropriately grounded anti-static workstation. Devices need careful handling using correctly designed collets, vacuum pickup tips or sharp antistatic tweezers to deter ESD damage to dice.
- Die Attach**
The die mounting surface must be clean and flat. Using conductive silver filled epoxy, recommended epoxies are DieMat DM6030HK-PT/H579 or Ablestik 84-1LMISR4. Apply sufficient epoxy to meet required epoxy bond line thickness, epoxy fillet height and epoxy coverage around total die periphery. Parts shall be cured in a nitrogen filled atmosphere per manufacturer's cure condition. It is recommended to use antistatic die pick up tools only.
- Wire Bonding**
Bond pad openings in the surface passivation above the bond pads are provided to allow wire bonding to the dice gold bond pads. Thermosonic bonding is used with minimized ultrasonic content. Bond force, time, ultrasonic power and temperature are all critical parameters. Suggested wire is pure gold, 1 mil diameter. Bonds must be made from the bond pads on the die to the package or substrate. All bond wires should be kept as short as low as reasonable to minimize performance degradation due to undesirable series inductance.

Assembly Diagram



Note: Ground bond wires are optional.

Recommended Wire Length, Typical

Wire	Wire Length (mm)	Wire Loop Height (mm)
RF-IN,	0.60	0.15
RF-OUT & DC-IN	1.00	0.30

Additional Detailed Technical Information <i>additional information is available on our dash board.</i>	
Performance Data	Data Table
	Swept Graphs
	S-Parameter (S2P Files) Data Set with and without port extension(.zip file)
Case Style	Die
Die Ordering and packaging information	Quantity, Package Model No.
	Small, Gel - Pak: 5,10,50,100 KGD* PMA2-153LN-DG+ Medium†, Partial wafer: KGD* <2580 PMA2-153LN-DP+ Large†, Full Wafer PMA2-153LN-DF+
	† Available upon request contact sales representative
	Refer to AN-60-067
Environmental Ratings	ENV-80

*Known Good Dice ("KGD") means that the dice in question have been subjected to Mini-Circuits DC test performance criteria and measurement instructions and that the parametric data of such dice fall within a predefined range. While DC testing is not definitive, it does help to provide a higher degree of confidence that dice are capable of meeting typical RF electrical parameters specified by Mini-Circuits.

ESD Rating**

Human Body Model (HBM): Class 1A (250 to <500V) in accordance with ANSI/ESD STM 5.1 - 2001

** Tested in industry standard 2x2mm, 8-lead MCLP package.

Additional Notes

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